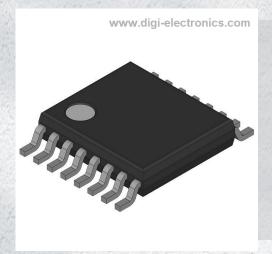


74HCT165PW-Q100118 Datasheet



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DiGi Electronics Part Number 74HCT165PW-Q100118-DG

Manufacturer NXP USA Inc.

Manufacturer Product Number 74HCT165PW-Q100118

Description PARALLEL IN SERIAL OUT, 8-BIT

Detailed Description Shift Shift Register 1 Element 8 Bit 16-TSSOP



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RFQ Email: Info@DiGi-Electronics.com

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
74HCT165PW-Q100118	NXP USA Inc.
Series:	Product Status:
74HCT	Active
Logic Type:	Output Type:
Shift Register	Complementary
Number of Elements:	Number of Bits per Element:
1	8
Function:	Voltage - Supply:
Parallel or Serial to Serial	4.5V ~ 5.5V
Operating Temperature:	Grade:
-40°C ~ 125°C	Automotive
Qualification:	Mounting Type:
AEC-Q100	Surface Mount
Package / Case:	Supplier Device Package:
16-TSSOP (0.173", 4.40mm Width)	16-TSSOP
Base Product Number:	
74HCT165	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
Not applicable	3 (168 Hours)
REACH Status:	ECCN:
Vendor Undefined	EAR99
HTSUS:	
8542.39.0001	

8-bit parallel-in/serial out shift register

Rev. 3 — 23 April 2020

Product data sheet

1. General description

The 74HC165-Q100; 74HCT165-Q100 are 8-bit serial or parallel-in/serial-out shift registers. The device features a serial data input (DS), eight parallel data inputs (D0 to D7) and two complementary serial outputs (Q7 and $\overline{\text{Q7}}$). When the parallel load input ($\overline{\text{PL}}$) is LOW the data from D0 to D7 is loaded into the shift register asynchronously. When $\overline{\text{PL}}$ is HIGH data enters the register serially at DS. When the clock enable input ($\overline{\text{CE}}$) is LOW data is shifted on the LOW-to-HIGH transitions of the CP input. A HIGH on $\overline{\text{CE}}$ will disable the CP input. Inputs are overvoltage tolerant to 15 V. This enables the device to be used in HIGH-to-LOW level shifting applications.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Asynchronous 8-bit parallel load
- · Synchronous serial input
- · Complies with JEDEC standard no. 7A
- Input levels:
 - For 74HC165-Q100: CMOS level
 - For 74HCT165-Q100: TTL level
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- DHVQFN package with Side-Wettable Flanks enabling Automatic Optical Inspection (AOI) of solder joints

3. Applications

Parallel-to-serial data conversion

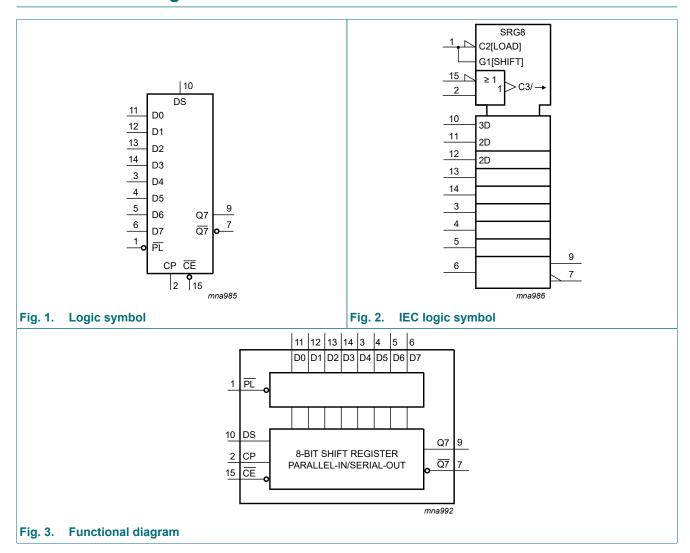


4. Ordering information

Table 1. Ordering information

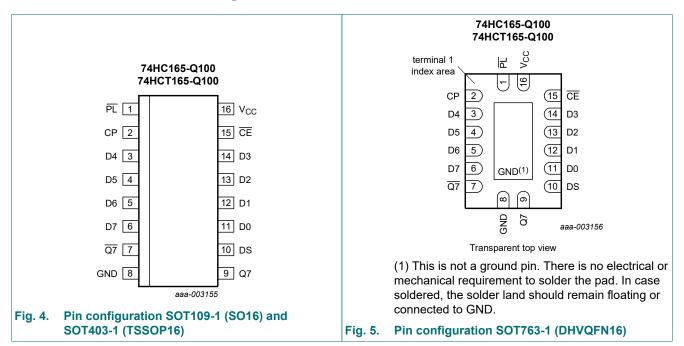
Type number	Package									
	Temperature range	Name	Description	Version						
74HC165D-Q100	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1						
74HCT165D-Q100			body width 3.9 mm							
74HC165PW-Q100	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1						
74HCT165PW-Q100			body width 4.4 mm							
74HC165BQ-Q100	-40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced	SOT763-1						
74HCT165BQ-Q100			very thin quad flat package; no leads; 16 terminals; body 2.5 × 3.5 × 0.85 mm							

5. Functional diagram



6. Pinning information

6.1. Pinning



6.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
PL	1	asynchronous parallel load input (active LOW)
CP	2	clock input (LOW-to-HIGH edge-triggered)
Q7	7	complementary output from the last stage
GND	8	ground (0 V)
Q7	9	serial output from the last stage
DS	10	serial data input
D0 to D7	11, 12, 13, 14, 3, 4, 5, 6	parallel data inputs (also referred to as Dn)
CE	15	clock enable input (active LOW)
V _{CC}	16	positive supply voltage

7. Functional description

Table 3. Function table

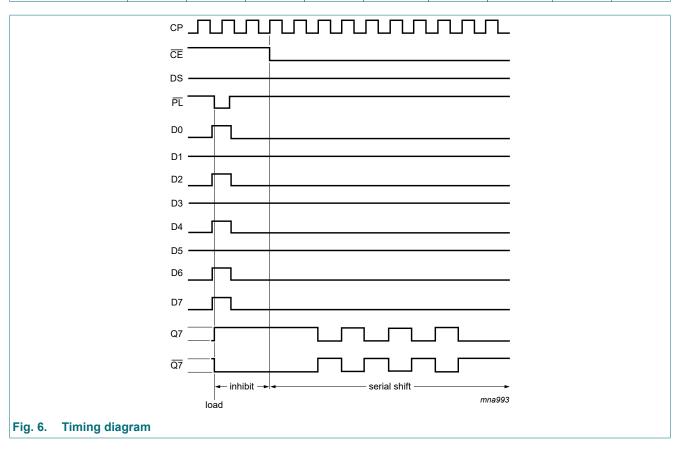
H = HIGH voltage level; h = HIGH voltage level one set-up time prior to the LOW-to-HIGH clock transition;

L = LOW voltage level; I = LOW voltage level one set-up time prior to the LOW-to-HIGH clock transition;

q = state of the referenced output one set-up time prior to the LOW-to-HIGH clock transition;

 $X = don't care; \uparrow = LOW-to-HIGH clock transition.$

Operating modes	Inputs	Inputs					sters	Output	Outputs	
	PL	CE	СР	DS	D0 to D7	Q0	Q1 to Q6	Q7	Q7	
parallel load	L	Х	Х	Х	L	L	L to L	L	Н	
	L	Х	Х	Х	Н	Н	H to H	Н	L	
serial shift	Н	L	1	I	X	L	q0 to q5	q6	q6	
	Н	L	1	h	Х	Н	q0 to q5	q6	q6	
	Н	1	L	I	Х	L	q0 to q5	q6	q6	
	Н	1	L	h	Х	Н	q0 to q5	q6	q6	
hold "do nothing"	do nothing" H H X X X		q0	q1 to q6	q7	q7				
	Н	Х	Н	Х	Х	q0	q1 to q6	q7	q7	



8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$ [1]	-	±20	mA
I _{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$ [1]	-	±20	mA
Io	output current	-0.5 V < V _O < V _{CC} + 0.5 V	-	±25	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$ [2]	-	500	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

9. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	741	74HC165-Q100			ICT165-C	2100	Unit
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	-	+125	-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
		V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V

10. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter Conditions		25 °C			-40 ° +85	C to	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC16	5-Q100									
V_{IH}	HIGH-level input	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V_{IL}	LOW-level input	V _{CC} = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V

^[2] For SOT109-1 (SO16) package: P_{tot} derates linearly with 12.4 mW/K above 110 °C.

For SOT403-1 (TSSOP16) package: Ptot derates linearly with 8.5 mW/K above 91 °C.

For SOT763-1 (DHVQFN16) package: Ptot derates linearly with 11.2 mW/K above 106 °C.

8-bit parallel-in/serial out shift register

Symbol	Parameter	Conditions		25 °C		_	°C to 5 °C		°C to 25 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
V _{OH}	HIGH-level	V _I = V _{IH} or V _{IL}								
	output voltage	I _O = -20 μA; V _{CC} = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	٧
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	٧
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	٧
		I _O = -4.0 mA; V _{CC} = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		I _O = -5.2 mA; V _{CC} = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
V _{OL}	LOW-level	V _I = V _{IH} or V _{IL}								
	output voltage	I _O = 20 μA; V _{CC} = 2.0 V	-	0	0.1	-	0.1	-	0.1	٧
		I _O = 20 μA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	-	0.1	٧
		I _O = 20 μA; V _{CC} = 6.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1	-	±1	μΑ
I _{CC}	supply current	V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 6.0 V	-	-	8.0	-	80	-	160	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT1	65-Q100									
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	8.0	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V
V _{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	I _O = 20 μA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	-	0.1	٧
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	٧
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1	-	±1	μΑ
I _{CC}	supply current	V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 6.0 V	-	-	8.0	-	80	-	160	μΑ
ΔI _{CC}	additional supply current	per input pin; V _I = V _{CC} - 2.1 V; other inputs at V _{CC} or GND; V _{CC} = 4.5 V to 5.5 V								
		Dn and DS inputs	-	35	126	-	157.5	-	171.5	μΑ
		CP, CE, and PL inputs	-	65	234	-	292.5	-	318.5	μA
Cı	input capacitance		-	3.5	-	-	-	-	-	pF

8-bit parallel-in/serial out shift register

11. Dynamic characteristics

Table 7. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); $C_L = 50$ pF unless otherwise specified; for test circuit, see Fig. 12

Symbol	Parameter	Conditions		25 °C			°C to 5 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC16	5-Q100									
t _{pd}	propagation	CP or CE to Q7, Q7; see Fig. 7 [1]								
	delay	V _{CC} = 2.0 V	-	52	165	-	205	-	250	ns
		V _{CC} = 4.5 V	-	19	33	-	41	-	50	ns
		V _{CC} = 6.0 V	-	15	28	-	35	-	43	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	16	-	-	-	-	-	ns
		PL to Q7, Q7; see Fig. 8								
		V _{CC} = 2.0 V	-	50	165	-	205	-	250	ns
		V _{CC} = 4.5 V	-	18	33	-	41	-	50	ns
		V _{CC} = 6.0 V	-	14	28	-	35	-	43	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	15	-	-	-	-	-	ns
		D7 to Q7, Q7; see Fig. 9								
		V _{CC} = 2.0 V	-	36	120	-	150	-	180	ns
		V _{CC} = 4.5 V	-	13	24	-	30	-	36	ns
		V _{CC} = 6.0 V	-	10	20	-	26	-	31	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	11	-	-	-	-	-	ns
t _t	transition time	Q7, Q7 output; see Fig. 7 [2]								
		V _{CC} = 2.0 V	-	19	75	-	95	-	110	ns
		V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
		V _{CC} = 6.0 V	-	6	13	-	16	-	19	ns
t _W	pulse width	CP input HIGH or LOW; see Fig. 7								
		V _{CC} = 2.0 V	80	17	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	6	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	5	-	17	-	20	-	ns
		PL input LOW; see Fig. 8								
		V _{CC} = 2.0 V	80	14	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	5	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	4	-	17	-	20	-	ns
t _{rec}	recovery time	PL to CP, CE; see Fig. 8								
		V _{CC} = 2.0 V	100	22	-	125	-	150	-	ns
		V _{CC} = 4.5 V	20	8	-	25	-	30	-	ns
		V _{CC} = 6.0 V	17	6	-	21	-	26	-	ns

8-bit parallel-in/serial out shift register

Symbol	Parameter	Conditions		25 °C			°C to		°C to 5 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
t _{su}	set-up time	DS to CP, CE; see Fig. 10								
		V _{CC} = 2.0 V	80	11	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	4	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	3	-	17	-	20	-	ns
		CE to CP and CP to CE; see Fig. 10								
		V _{CC} = 2.0 V	80	17	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	6	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	5	-	17	-	20	-	ns
		Dn to PL; see Fig. 11								
		V _{CC} = 2.0 V	80	22	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	8	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	6	-	17	-	20	-	ns
t _h	hold time	DS to CP, CE and Dn to PL; see Fig. 10								
		V _{CC} = 2.0 V	5	2	-	5	-	5	-	ns
		V _{CC} = 4.5 V	5	2	-	5	-	5	-	ns
		V _{CC} = 6.0 V	5	2	-	5	-	5	-	ns
		CE to CP and CP to CE; see Fig. 10								
		V _{CC} = 2.0 V	5	-17	-	5	-	5	-	ns
		V _{CC} = 4.5 V	5	-6	-	5	-	5	-	ns
		V _{CC} = 6.0 V	5	-5	-	5	-	5	-	ns
f _{max}	maximum	CP input; see Fig. 7								
	frequency	V _{CC} = 2.0 V	6	17	-	5	-	4	-	MHz
		V _{CC} = 4.5 V	30	51	-	24	-	20	-	MHz
		V _{CC} = 6.0 V	35	61	-	28	-	24	-	MHz
		V _{CC} = 5.0 V; C _L = 15 pF	-	56	-	-	-	-	-	MHz
C _{PD}	power dissipation capacitance	per package; V _I = GND to V _{CC} [3]	-	35	-	-	-	-	-	pF
74HCT1	65-Q100									
t _{pd}	propagation	CE, CP to Q7, Q7; see Fig. 7 [1]								
	delay	V _{CC} = 4.5 V	-	17	34	-	43	-	51	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	14	_	-	-	-	-	ns
		PL to Q7, Q7; see Fig. 8								
		V _{CC} = 4.5 V	-	20	40	-	50	-	60	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	17	-	-	-	-	-	ns
		D7 to Q7, Q7; see Fig. 9								
		V _{CC} = 4.5 V	-	14	28	-	35	-	42	ns
		V _{CC} = 5.0 V; C _L = 15 pF	_	11	_	-	-	_	_	ns

8-bit parallel-in/serial out shift register

Symbol	Parameter	Conditions		25 °C			°C to 5 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
t _t	transition time	Q7, Q7 output; see Fig. 7 [2]								
		V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
t _W	pulse width	CP input; see Fig. 7								
		V _{CC} = 4.5 V	16	6	-	20	-	24	-	ns
		PL input; see Fig. 8								
		V _{CC} = 4.5 V	20	9	-	25	-	30	-	ns
t _{rec}	recovery time	PL to CP, CE; see Fig. 8								
		V _{CC} = 4.5 V	20	8	-	25	-	30	-	ns
t _{su}	set-up time	DS to CP, CE; see Fig. 10								
		V _{CC} = 4.5 V	20	2	-	25	-	30	-	ns
		CE to CP and CP to CE; see Fig. 10								
		V _{CC} = 4.5 V	20	7	-	25	-	30	-	ns
		Dn to PL; see Fig. 11								
		V _{CC} = 4.5 V	20	10	-	25	-	30	-	ns
t _h	hold time	DS to CP, CE and Dn to PL; see Fig. 10								
		V _{CC} = 4.5 V	7	-1	-	9	-	11	-	ns
		CE to CP and CP to CE; see Fig. 10								
		V _{CC} = 4.5 V	0	-7	-	0	-	0	-	ns
f _{max}	maximum frequency	CP input; see Fig. 7								
		V _{CC} = 4.5 V	26	44	-	21	-	17	-	MHz
		V _{CC} = 5.0 V; C _L = 15 pF	-	48	-	-	-	-	-	MHz
C _{PD}	power dissipation capacitance	per package; [3] V _I = GND to V _{CC} - 1.5 V	-	35	-	-	-	-	-	pF

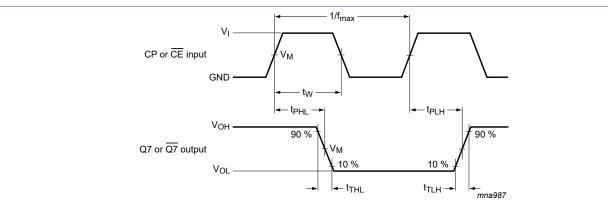
f_i = input frequency in MHz;

f_o = output frequency in MHz;

 Σ (C_L × V_{CC}² × f_o) = sum of outputs; C_L = output load capacitance in pF;

V_{CC} = supply voltage in V.

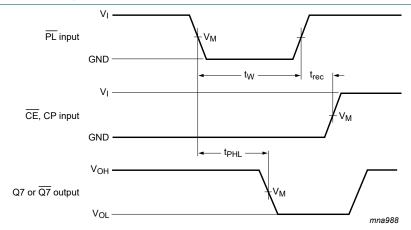
11.1. Waveforms and test circuit



Measurement points are given in <u>Table 8</u>.

V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

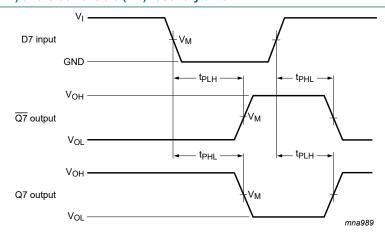
Fig. 7. The clock (CP) or clock enable (CE) to output (Q7 or Q7) propagation delays, the clock pulse width, the maximum clock frequency and the output transition times



Measurement points are given in Table 8.

V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig. 8. The parallel load (PL) pulse width, the parallel load to output (Q7 or Q7) propagation delays, the parallel load to clock (CP) and clock enable (CE) recovery time

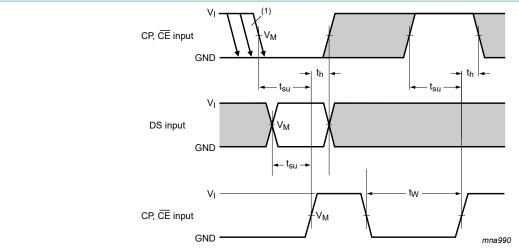


Measurement points are given in Table 8.

 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig. 9. The data input (D7) to output (Q7 or $\overline{Q7}$) propagation delays when \overline{PL} is LOW

8-bit parallel-in/serial out shift register

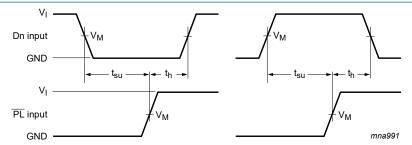


(1) $\overline{\text{CE}}$ may change only from HIGH-to-LOW while CP is LOW.

The shaded areas indicate when the input is permitted to change for predictable output performance Measurement points are given in <u>Table 8</u>.

 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig. 10. The set-up and hold times from the serial data input (DS) to the clock (CP) and clock enable (CE) inputs, from the clock enable input (CE) to the clock input (CP) and from the clock input (CP) to the clock enable input (CE)



Measurement points are given in Table 8.

V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

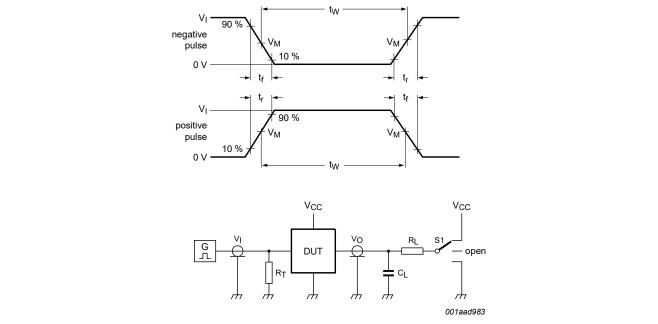
Fig. 11. The set-up and hold times from the data inputs (Dn) to the parallel load input (PL)

Table 8. Measurement points

Туре	Input	Output	
	V _I	V _M	V _M
74HC165-Q100	V _{CC}	0.5V _{CC}	0.5V _{CC}
74HCT165-Q100	3 V	1.3 V	1.3 V

Product data sheet

8-bit parallel-in/serial out shift register



Test data is given in Table 9.

Definitions for test circuit:

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

C_L = Load capacitance including jig and probe capacitance.

 R_{l} = Load resistance.

S1 = Test selection switch

Fig. 12. Test circuit for measuring switching times

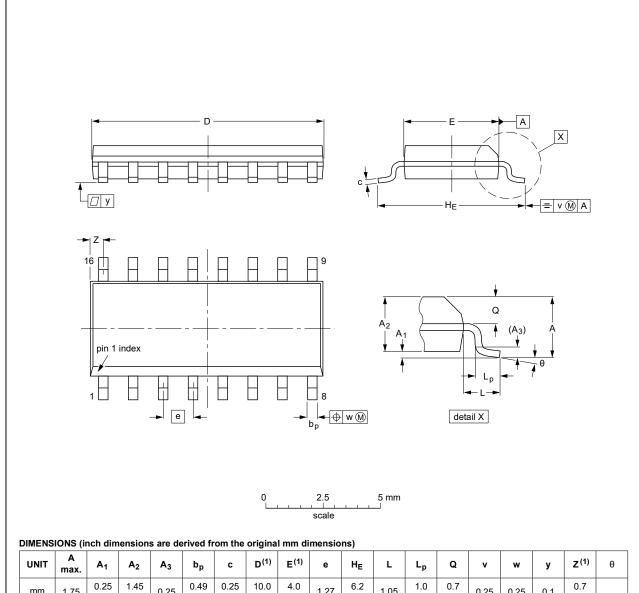
Table 9. Test data

Туре	Input		Load	S1 position	
	V _I	t _r , t _f	C _L	R_L	t _{PHL} , t _{PLH}
74HC165-Q100	V _{CC}	6 ns	15 pF, 50 pF	1 kΩ	open
74HCT165-Q100	3 V	6 ns	15 pF, 50 pF	1 kΩ	open

12. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.39 0.38	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	0°

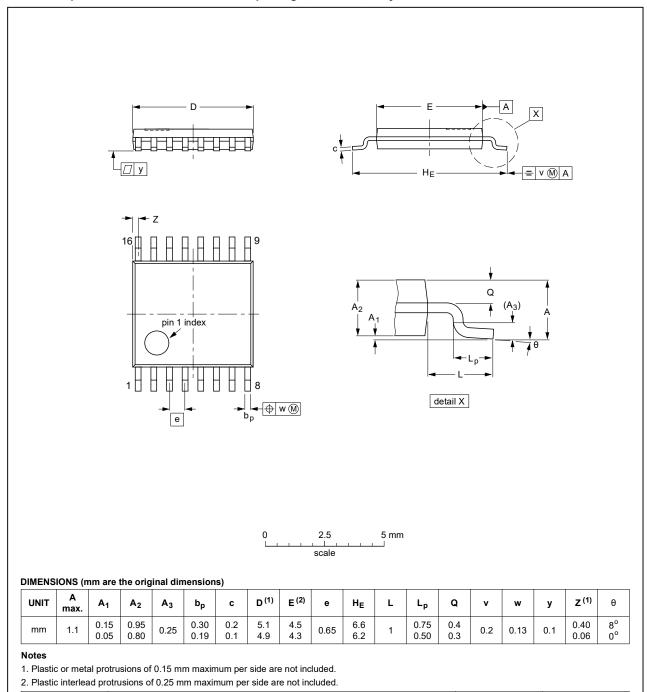
1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012				99-12-27 03-02-19	

Fig. 13. Package outline SOT109-1 (SO16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT403-1		MO-153				99-12-27 03-02-18

Fig. 14. Package outline SOT403-1 (TSSOP16)

DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

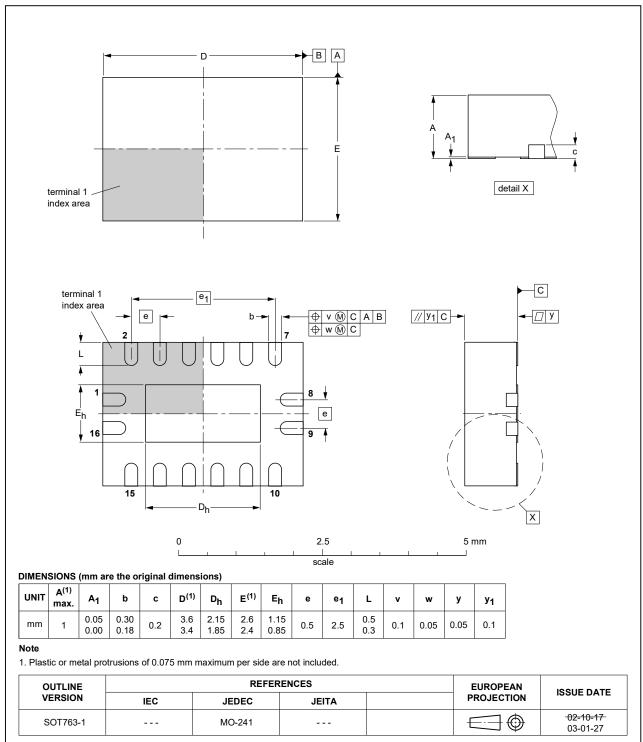


Fig. 15. Package outline SOT763-1 (DHVQFN16)

13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MIL	Military
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74HC_HCT165_Q100 v.3	20200423	Product data sheet	-	74HC_HCT165_Q100 v.2		
Modifications:	 <u>Section 2</u> updated. <u>Table 4</u>: Derating values for P_{tot} total power dissipation updated. 					
74HC_HCT165_Q100 v.2	20170821	Product data sheet	-	74HC_HCT165_Q100 v.1		
Modifications:	The format of t Nexperia.	ated. ime for 74HC165 has been up this data sheet has been redes we been adapted to the new co	igned to comply with			
74HC_HCT165_Q100 v.1	20120717	Product data sheet	-	-		

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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Date of release: 23 April 2020

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